## NSN 5961-01-005-4597

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View Online at https://aerobasegroup.com/nsn/5961-01-005-4597 **Inclosure Material:** Metal **Overall Length:** 39.5 millimeters **Overall Height:** 9.5 millimeters **Overall Width:** 26.6 millimeters **Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method: Terminal Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 55.0 breakdown voltage, collector-to-base, emitter open and 7.0 breakdown voltage, emitter-to-base, collector open and 45.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 10.00 amperes source cutoff current and 7.00 amperes source cutoff current **Power Rating Per Characteristic:** 78.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: